

## 1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 plastic package intended for use in applications requiring good bidirectional blocking voltage capability and high thermal cycling performance.

## 2. Features and benefits

- Good bidirectional blocking voltage capability
- High thermal cycling performance

### 3. Applications

- Ignition circuits
- Motor control
- Protection circuits
- Voltage regulation

## 4. Quick reference data

Table 1. Quick	reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	800	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	800	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	100	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	-	110	A
Tj	junction temperature		-	-	125	°C
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 109 °C; <u>Fig. 1</u>	-	-	7.5	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 109 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	12	A
Static charact	eristics	·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	2	15	mA
Dynamic char	acteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$\label{eq:VDM} \begin{array}{l} V_{DM} = 335 \; V; \; T_{j} = 125 \; ^{\circ}C; \; R_{GK} = 100 \; \Omega; \\ (V_{DM} = 67\% \; of \; V_{DRM}); \; expoential \\ waveform; \; \underline{Fig. 12} \end{array}$	200	1000	-	V/µs

## 5. Pinning information

Table 2. F	Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	а <del>-Ы</del> -к
2	А	anode		G sym037
3	G	gate		Symoor
mb	A	mounting base; connected to anode	TO-220AB (SOT78)	

# 6. Ordering information

Table 3. Ordering infor	mation				
Type number	Package				
	Name	Description	Version		
BT151-800C	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

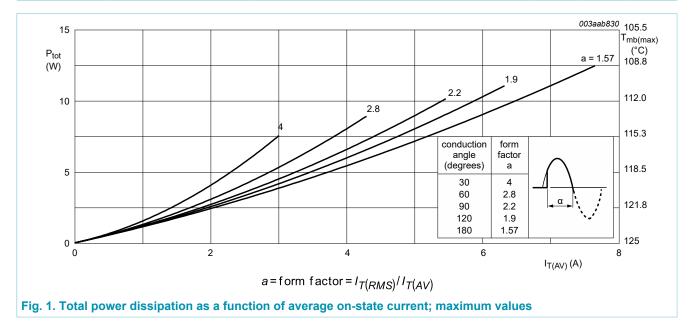
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### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

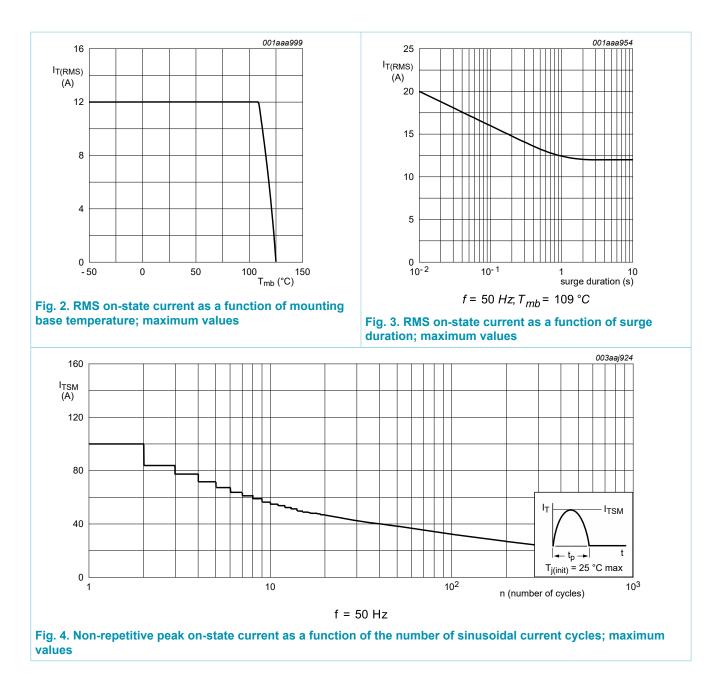
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	800	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	800	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 109 °C; <u>Fig. 1</u>	-	7.5	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{mb} \le 109 \text{ °C}$ ; <u>Fig. 2;</u> Fig. 3	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	100	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	110	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN	-	50	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 30 mA	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	2	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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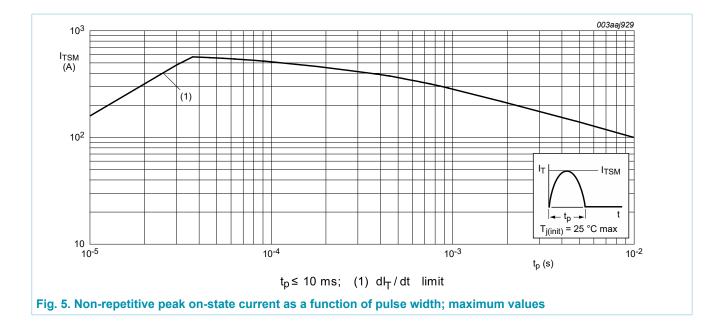
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### 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. <u>6</u>	-	-	1.3	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

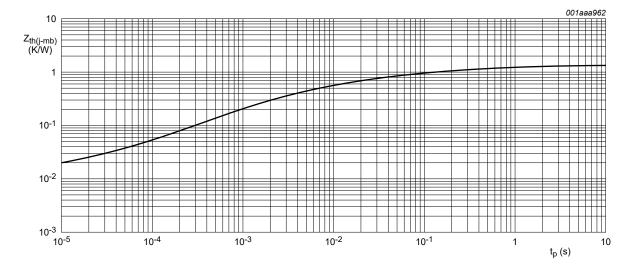


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse width

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### 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · ·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	2	15	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C}; \text{ Fig. 8}$	-	10	40	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	7	20	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 23 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.44	1.75	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 11	-	0.6	1.5	V
		V <sub>D</sub> = 500 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 11	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 500 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 500 V; T <sub>j</sub> = 125 °C	-	0.1	0.5	mA
Dynamic ch	aracteristics		· ·			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$      V_{DM} = 335 \text{ V};  \text{T}_{j} = 125 ^{\circ}\text{C};  \text{R}_{GK} = 100  \Omega; \\       (\text{V}_{DM} = 67\% \text{ of } \text{V}_{DRM}); \text{ expoential} \\       waveform; \underline{\text{Fig. } 12} $	200	1000	-	V/µs
		$V_{DM}$ = 335 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 12	50	130	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 40 A; V <sub>D</sub> = 500 V; I <sub>G</sub> = 0.1 A; dI <sub>G</sub> / dt = 5 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	70	-	μs

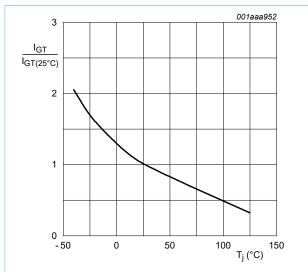
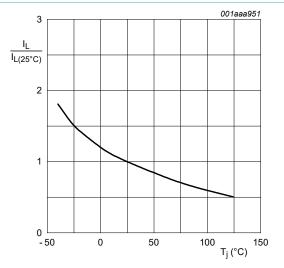


Fig. 7. Normalized gate trigger current as a function of junction temperature

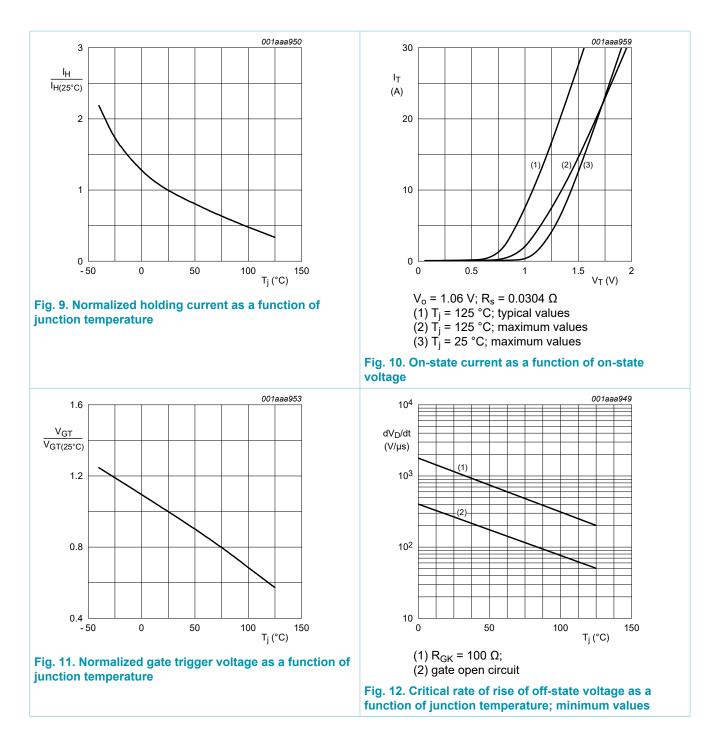




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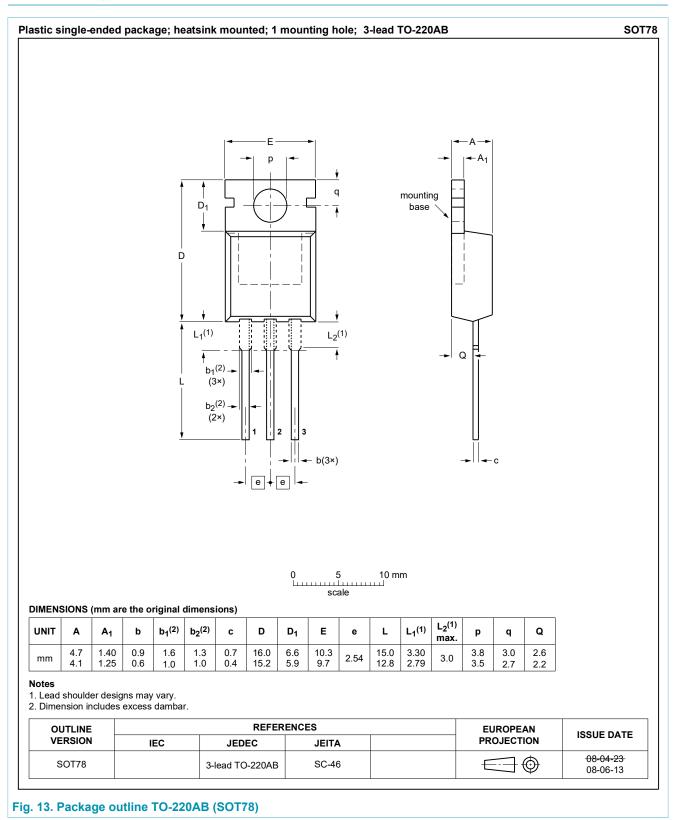
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### 10. Package outline



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## 11. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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